

2SK1161, 2SK1162

Silicon N-Channel MOS FET

Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator and DC-DC converter

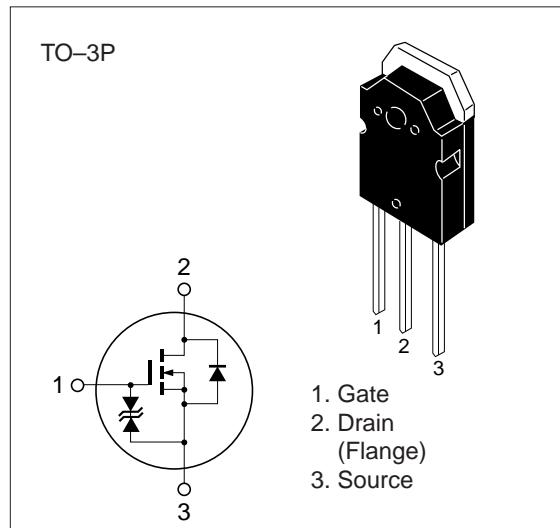


Table 1 Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage 2SK1161	V _{DSS}	450	V
		500	
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	10	A
Drain peak current	I _{D(pulse)} *	30	A
Body to drain diode reverse drain current	I _{DR}	10	A
Channel dissipation	P _{ch} **	100	W
Channel temperature	T _{ch}	150	°C
Storage temperature	T _{stg}	-55 to +150	°C

* PW ≤ 10 µs, duty cycle ≤ 1 %

** Value at T_C = 25 °C

Table 2 Electrical Characteristics (Ta = 25°C)

Item		Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	2SK1161	V _{(BR)DSS}	450	—	—	V	I _D = 10 mA, V _{GS} = 0
	2SK1162		500				
Gate to source breakdown voltage		V _{(BR)GSS}	±30	—	—	V	I _G = ±100 µA, V _{DS} = 0
Gate to source leak current		I _{GSS}	—	—	±10	µA	V _{GS} = ±25 V, V _{DS} = 0
Zero gate voltage drain current	2SK1161	I _{DSS}	—	—	250	µA	V _{DS} = 360 V, V _{GS} = 0
	2SK1162						V _{DS} = 400 V, V _{GS} = 0
Gate to source cutoff voltage		V _{GS(off)}	2.0	—	3.0	V	I _D = 1 mA, V _{DS} = 10 V
Static Drain to source on state resistance	2SK1161	R _{DS(on)}	—	0.6	0.8	Ω	I _D = 5 A, V _{GS} = 10 V *
	2SK1162		—	0.7	0.9		
Forward transfer admittance		y _{fs}	4.0	7.0	—	S	I _D = 5 A, V _{DS} = 10 V *
Input capacitance		C _{iss}	—	1050	—	pF	V _{DS} = 10 V, V _{GS} = 0,
Output capacitance		C _{oss}	—	280	—	pF	f = 1 MHz
Reverse transfer capacitance		C _{rss}	—	40	—	pF	
Turn-on delay time		t _{d(on)}	—	15	—	ns	I _D = 5 A, V _{GS} = 10 V,
Rise time		t _r	—	60	—	ns	R _L = 6 Ω
Turn-off delay time		t _{d(off)}	—	90	—	ns	
Fall time		t _f	—	45	—	ns	
Body to drain diode forward voltage		V _{DF}	—	1.0	—	V	I _F = 10 A, V _{GS} = 0
Body to drain diode reverse recovery time		t _{rr}	—	350	—	ns	I _F = 10 A, V _{GS} = 0, di _F /dt = 100 A/µs

* Pulse Test

See characteristic curves of 2SK1157, 2SK1158.

